



Amendments to the Claims:

This listing of the claims will replace all prior versions and listings of claims in the application:

Listing of Claims:

1 (Currently Amended): A negative electrode active material for a non-aqueous electrolyte rechargeable battery capable of absorbing/desorbing lithium comprising: an inner layer comprising at least a material selected from the group consisting of Si, ~~Sn~~, and an alloy containing Si ~~and an alloy containing Sn~~; and a surface layer comprising silicon oxide ~~or tin oxide~~ of 0.2 to 1,000 nm in average thickness formed on said inner layer.

2 (Original): The negative electrode active material in accordance with claim 1, wherein the average thickness of said surface layer is 1 to 100 nm.

3 (Original): The negative electrode active material in accordance with claim 1, wherein the average thickness of said surface layer is 1 to 10 nm.

4 (Original): The negative electrode active material in accordance with claim 1, wherein said surface layer has a thickness in the range of $\pm 50\%$ of the average thickness.

5 (Currently Amended): The negative electrode active material in accordance with claim 1, wherein said alloy comprises Si ~~or Sn~~ and at least an element selected from the group consisting of Ti, Co, Ni, Cu, Mg, Zr, V, Mo, W, Mn and Fe.

6 (Currently Amended): The negative electrode active material in accordance with claim 1, wherein said alloy comprises at least an Si phase ~~or an Sn phase~~ and an alloy phase containing at least an element selected from the group consisting of Ti, Co, Ni, Cu, Mg, Zr, V, Mo, W, Mn and Fe.

7 (Original): The negative electrode active material in accordance with claim 1, which is in the form of a thin film or powder.

8 (Original): The negative electrode active material in accordance with claim 1 including an amorphous Si phase.

9 (Currently Amended): A non-aqueous electrolyte rechargeable battery using a negative electrode active material capable of absorbing/desorbing lithium comprising: an inner layer comprising at least a material selected from the group consisting of Si, ~~Sn~~, and an alloy containing Si ~~and an alloy containing Sn~~; and a surface layer comprising silicon oxide ~~or tin oxide~~ of 0.2 to 1,000 nm in average thickness formed on said inner layer.